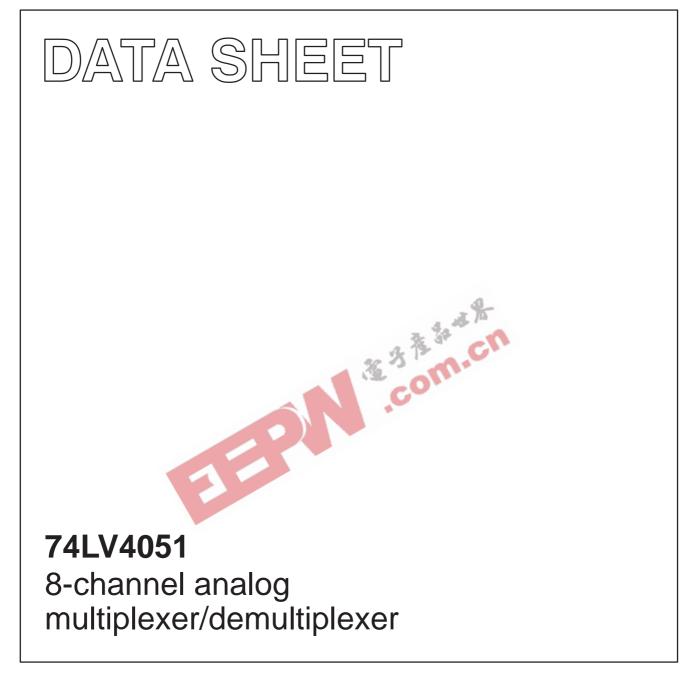
# INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Jul 15 IC24 Data Handbook 1998 Jun 23



# 74LV4051

### **FEATURES**

- Optimized for low voltage applications: 1.0 to 6.0 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Low typ "ON" resistance:
- $\begin{array}{l} 60 \ \Omega \ \text{at} \ \text{V}_{\text{CC}} \text{V}_{\text{EE}} = 4.5 \ \text{V} \\ 90 \ \Omega \ \text{at} \ \text{V}_{\text{CC}} \text{V}_{\text{EE}} = 3.0 \ \text{V} \\ 145 \ \Omega \ \text{at} \ \text{V}_{\text{CC}} \text{V}_{\text{EE}} = 2.0 \ \text{V} \end{array}$
- Logic level translation: to enable 3 V logic to communicate with ± 3 V analog signals
- Typical "break before make" built in
- Output capability: non-standard
- I<sub>CC</sub> category: MSI

#### DESCRIPTION

The 74LV4051 is a low-voltage CMOS device and is pin and function compatible with the 74HC/HCT4051.

The 74LV4051 is an 8-channel analog multiplexer/demultiplexer with three digital select inputs ( $S_0$  to  $S_2$ ) an active LOW enable input (E), eight independent inputs/outputs ( $Y_0$  to  $Y_7$ ) and a common inputs/outputs ( $Y_0$  to  $Y_7$ ). input/output (Z).

With  $\overline{E}$  LOW, one of the eight switches is selected (low impedance ON-state) by  $S_0$  to  $S_2$ . With  $\overline{E}$  HIGH, all switches are in the high impedance OFF-state, independent of  $S_0$  to  $S_2$ .

 $V_{CC}$  and GND are the supply voltage pins for the digital control inputs (S<sub>0</sub> to S<sub>2</sub>, and Ē). The V<sub>CC</sub> to GND ranges are 1.0 to 6.0 V. The analog inputs/outputs (Y<sub>0</sub> to Y<sub>7</sub> and Z) can swing between V<sub>CC</sub> as a positive limit and V<sub>EE</sub> as a negative limit. V<sub>CC</sub> - V<sub>EE</sub> may not exceed 6.0 V. For operation as a digital multiplexer/demultiplexer, V<sub>CE</sub> is connected to GND (typical) around). V<sub>EE</sub> is connected to GND (typically ground).

## QUICK REFERENCE DATA

$GND = 0 V; I_{i}$	<sub>amb</sub> = 25°C; t <sub>r</sub> =t <sub>f</sub> ≤ 2.5 ns	- B		
SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t <sub>PZH</sub> /t <sub>PZL</sub>	Turn "ON" time E to $V_{OS}$ S <sub>n</sub> to $V_{OS}$	$C_L = 15 \text{ pF}$ $R_L = 1K\Omega$ $V_{CC} = 3.3 \text{ V}$	23 22	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn "OFF" time $\overline{E}$ to V <sub>OS</sub> S <sub>n</sub> to V <sub>OS</sub>	Contra	25 20	115
Cl	Input capacitance		3.5	
C <sub>PD</sub>	Power dissipation capacitance per switch	See Notes 1 and 2	25	pF
C <sub>S</sub>	Maximum switch capacitance independent (Y) common (Z)		5 25	

NOTES:

2.

 $\begin{array}{l} C_{PD} \text{ is used to determine the dynamic power dissipation } (P_{D} \text{ in } \mu W) \\ P_{D} = C_{PD} \times V_{CC}{}^{2} \times f_{i} + \overset{\frown}{\Sigma} ((C_{L} + C_{S}) \times V_{CC}{}^{2} \times f_{o}) \text{ where:} \\ f_{i} = \text{ input frequency in MHz; } C_{L} = \text{ output load capacity in } pF; \\ f_{o} = \text{ output frequency in MHz; } C_{S} = \text{maximum switch capacitance in } pF; \end{array}$ 1.

 $V_{CC}$  = supply voltage in V;  $\sum ((C_L + C_S) \times V_{CC}^2 \times f_o)$  = sum of the outputs. The condition is V<sub>I</sub> = GND to V<sub>CC</sub>.

## **ORDERING INFORMATION**

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	Code
16-Pin Plastic DIL	-40°C to +125°C	74LV4051 N	74LV4051 N	SOT38-4
16-Pin Plastic SO	-40°C to +125°C	74LV4051 D	74LV4051 D	SOT109-1
16-Pin Plastic SSOP Type II	-40°C to +125°C	74LV4051 DB	74LV4051 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +125°C	74LV4051 PW	74LV4051PW DH	SOT403-1

#### **PIN CONFIGURATION**

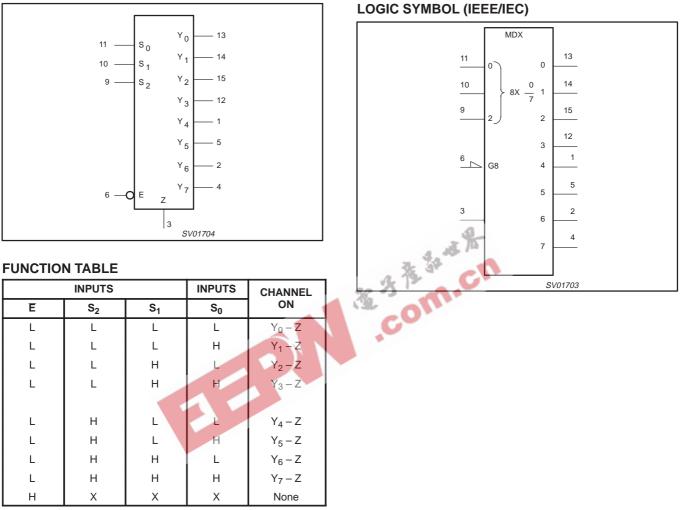
Y <sub>4</sub> 1		6 V <sub>CC</sub>
Y <sub>6</sub> 2	1	5 Y <sub>2</sub>
Z 3	1	4 Y <sub>1</sub>
Y <sub>7</sub> 4	1	3 Y <sub>0</sub>
Y <sub>5</sub> 5	1	2 Y <sub>3</sub>
Ē 6	1	1 S <sub>0</sub>
V <sub>EE</sub> 7	1	0 S <sub>1</sub>
GND 8	Ş	9 S <sub>2</sub>
	SV0	1702

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	FUNCTION				
3	Z	Common input/output				
6	Ē	Enable input (active LOW)				
7	V <sub>EE</sub>	Negative supply voltage				
8	GND	Ground (0 V)				
11, 10, 9	S <sub>0</sub> to S <sub>2</sub>	Select inputs				
13, 14, 15, 12, 1, 5, 2, 4	$Y_0$ to $Y_7$	Independent inputs/outputs				
16	V <sub>CC</sub>	Positive supply voltage				

# 74LV4051

## LOGIC SYMBOL



#### NOTES:

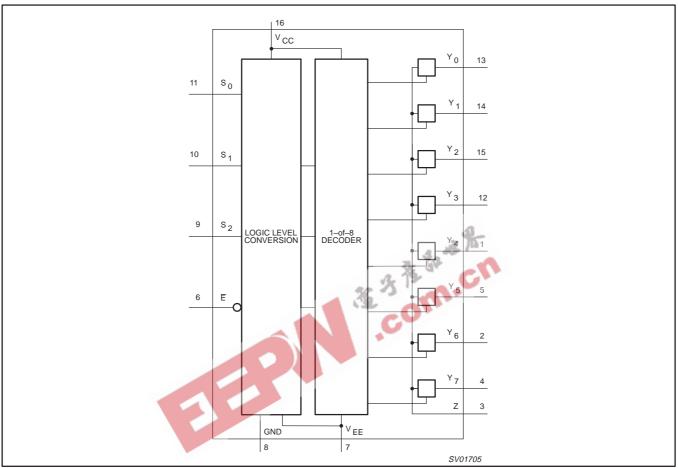
H = HIGH voltage level

L = LOW voltage level

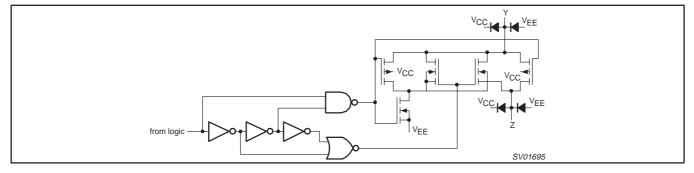
X = don't care

# 74LV4051

## FUNCTIONAL DIAGRAM



## SCHEMATIC DIAGRAM (ONE SWITCH)



# 74LV4051

#### **ABSOLUTE MAXIMUM RATINGS<sup>1, 2</sup>**

In accordance with the Absolute Maximum Rating System (IEC 134).

Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V <sub>CC</sub>	DC supply voltage		-0.5 to +7.0	V
$\pm I_{IK}$	DC input diode current	$V_{I} < -0.5 \text{ or } V_{I} > V_{CC} + 0.5 \text{ V}$	20	mA
$\pm I_{SK}$	DC switch diode current	$V_{\rm S}$ < -0.5 or $V_{\rm S}$ > $V_{\rm CC}$ + 0.5 V	20	mA
$\pm I_S$	DC switch current	$-0.5 \text{ V} < \text{V}_{\text{S}} < \text{V}_{\text{CC}} + 0.5 \text{ V}$	25	mA
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C
P <sub>TOT</sub>	Power dissipation per package – plastic DIL – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	for temperature range: -40 to +125°C above +70°C derate linearly with 12 mW/K above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	750 500 400	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## **RECOMMENDED OPERATING CONDITIONS**

RECOMMENDED OPERATING CONDITIONS											
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT					
V <sub>CC</sub>	DC supply voltage	See Note 1 and Figure 5	1.0	3.3	6.0	V					
VI	Input voltage	C	0	-	V <sub>CC</sub>	V					
Vo	Output voltage		0	-	V <sub>CC</sub>	V					
T <sub>amb</sub>	Operating ambient temperature range in free air	See DC and AC characteristics	-40 -40		+85 +125	°C					
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	$V_{CC} = 1.0 V \text{ to } 2.0 V$ $V_{CC} = 2.0 V \text{ to } 2.7 V$ $V_{CC} = 2.7 V \text{ to } 6.0 V$			500 200 100	ns/V					

NOTE:

1. The LV is guaranteed to function down to  $V_{CC} = 1.0V$  (input levels GND or  $V_{CC}$ ); DC characteristics are guaranteed from  $V_{CC} = 1.2V$  to  $V_{CC} = 6.0V$ .

# 74LV4051

### DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions, voltages are referenced to GND (ground = 0 V)

						LIMITS	_		
SYMBOL	PARAMETER	TEST CO	ONDITIONS	-4(	)°C to +8	5°C	-40°C to	o +125°C	
				MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1
		V <sub>CC</sub> = 1.2 V		0.9			0.9		
		V <sub>CC</sub> = 2.0 V		1.4			1.4		1
VIH	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6 V		2.0			2.0		V
	Voltage	V <sub>CC</sub> = 4.5 V		3.15			3.15		1
		V <sub>CC</sub> = 6.0 V		4.20			4.20		1
		V <sub>CC</sub> = 1.2 V				0.3		0.3	
		V <sub>CC</sub> = 2.0 V				0.6		0.6	1
VIL	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6 V				0.8		0.8	V
	Voltage	V <sub>CC</sub> = 4.5 V				1.35		1.35	1
		V <sub>CC</sub> = 6.0 V				1.80		1.80	1
	Input leakage	V <sub>CC</sub> = 3.6				1.0		1.0	
±II	current	$V_{CC} = 6.0$	$V_1 = V_{CC}$ or GND		1.0	2.0		2.0	- μΑ
	Analog switch	V <sub>CC</sub> = 3.6	$V_I = V_{IH} \text{ or } V_{IL}$	九陽	1	1.0		1.0	
±I <sub>S</sub>	OFF-state current per channel	V <sub>CC</sub> = 6.0	IV <sub>S</sub> I = V <sub>CC</sub> - GND (See Figure 2)		<b>N</b> .	2.0		2.0	- μΑ
	Analog switch	V <sub>CC</sub> = 3.6	$V_{I} = V_{IH} \text{ or } V_{IL}$	CO	1	1.0		1.0	
±ls	ON-state current	V <sub>CC</sub> = 6.0	IV <sub>S</sub> I = V <sub>CC</sub> - GND (See Figure 3)			2.0		2.0	μΑ
1	Quiescent supply	V <sub>CC</sub> = 3.6 V	$V_{I} = V_{CC}$ or GND			20.0		40	
Icc	current	$V_{\rm CC} = 6.0 \text{ V}$	$V_{IS} = GND \text{ or } V_{CC};$ $V_{OS} = V_{CC} \text{ or } GND$			40.0		80	μΑ
$\Delta I_{CC}$	Additional quiescent supply current per input	$V_{\rm CC} = 2.7$ to 3.6 V	V <sub>I</sub> = V <sub>CC</sub> – 0.6 V			500		850	μA
		V <sub>CC</sub> = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 \mu \text{A};$ $V_{IS} = V_{CC} \text{ to GND}$						
	ONI registeres	V <sub>CC</sub> = 2.0 V			145	325		375	1
R <sub>ON</sub>	ON-resistance (peak)	V <sub>CC</sub> = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		90	200		235	Ω
	(1 · · · · /	V <sub>CC</sub> = 3.0 to 3.6 V	$I_{\rm S} = 1000  {}_{\rm u}{\rm A};$		80	180		210	1
		V <sub>CC</sub> = 4.5 V	$V_{IS} = V_{CC}$ to GND		60	135		160	1
		V <sub>CC</sub> = 6.0 V	-		55	125		145	1
		V <sub>CC</sub> = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 _{\mu}\text{A};$ $V_{IS} = \text{GND}$		225				
	ON-resistance	V <sub>CC</sub> = 2.0 V			110	235		270	1
R <sub>ON</sub>	(rail)	V <sub>CC</sub> = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		70	145		165	Ω
		V <sub>CC</sub> = 3.0 to 3.6 V	$I_{S} = 1000  \mu A;$		60	130	İ 👘	150	1
		V <sub>CC</sub> = 4.5 V	V <sub>IS =</sub> GND		45	100	İ	115	1
		V <sub>CC</sub> = 6.0 V	1		40	85		100	1

NOTES:

All typical values are measured at T<sub>amb</sub> = 25°C.
 At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
 R<sub>ON</sub> (MAX) data is preliminary.

# 74LV4051

## DC ELECTRICAL CHARACTERISTICS (Continued)

						LIMITS			
SYMBOL	PARAMETER	TEST CO	NDITIONS	-4	0°C to +85	õ°C	-40°C to	UNIT	
				MIN	TYP <sup>1</sup>	MAX	MIN	MAX	1
		V <sub>CC</sub> = 1.2 V	$V_{I} = V_{IH} \text{ or } V_{IL};$ $I_{S} = 100 \ _{\mu}A;$ $V_{IS} = V_{CC}$		250				Ω
_	ON-resistance	V <sub>CC</sub> = 2.0 V			120	320		370	
R <sub>ON</sub>	(rail)	V <sub>CC</sub> = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		75	195		225	1
	V <sub>CC</sub> = 3.0 to 3.6 V	$I_{S} = 1000  \mu A;$		70	175		205	Ω	
		V <sub>CC</sub> = 4.5 V	$V_{IS} = V_{CC}$		50	130		150	1
		$V_{CC} = 6.0 V$			45	120		135	1
		V <sub>CC</sub> = 1.2 V							
	Maximum variation	V <sub>CC</sub> = 2.0 V			5				1
$\Delta R_{ON}$	of ON-resistance	V <sub>CC</sub> = 2.7 V	$V_{I} = V_{IH} \text{ or } V_{IL};$		4				Ω
ANON	between any two	V <sub>CC</sub> = 3.0 to 3.6 V	$V_{IS} = V_{CC}$ to GND		4				
	channels	V <sub>CC</sub> = 4.5 V	1		3	Sea.			1
		V <sub>CC</sub> = 6.0 V			2	~			1
	l values are measured	d at $T_{amb} = 25^{\circ}C.$		次落	30		oforo it io ro	<u>.</u>	

NOTES:
1. All typical values are measured at T<sub>amb</sub> = 25°C.
2. At supply voltages approaching 1.2 V, the analog switch ON-resistance becomes extremely non-linear. Therefore, it is recommended that these devices be used to transmit digital signals only, when using these supply voltages.
3. R<sub>ON</sub> (MAX) data is preliminary. , these

# 74LV4051

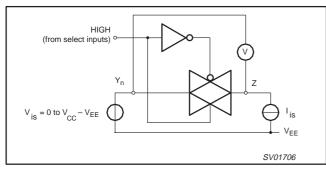


Figure 1. Test circuit for measuring ON-resistance ( $R_{ON}$ ).

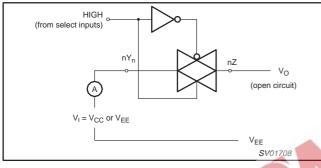


Figure 3. Test circuit for measuring ON-state current.

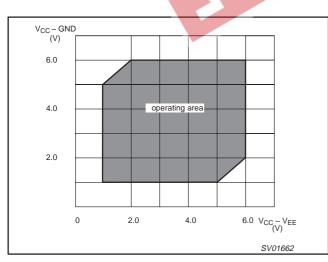


Figure 5. Guaranteed operating area as a function of the supply voltages.

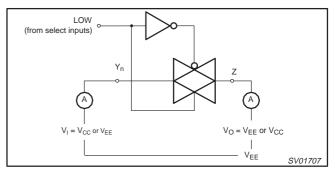


Figure 2. Test circuit for measuring OFF-state current.

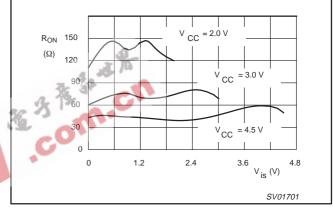


Figure 4. Typical ON-resistance ( $R_{on}$ ) as a function of input voltage ( $V_{is}$ ) for  $V_{is}$  = 0 to  $V_{CC} - V_{EE}$ .

# 74LV4051

## **AC CHARACTERISTICS**

 $GND = 0 \text{ V}; t_r = t_f \leq 2.5 ns; C_L = 50 pF$ 

		CONDITION	1			LIMITS			
SYMBOL	PARAMETER	CONDITION			40 to +85 °	С	-40 to -	+125 °C	UNIT
		V <sub>CC</sub> (V)	OTHER	MIN	TYP <sup>1</sup>	MAX	MIN	МАХ	
		1.2			25				
		2.0			9	17		20	
t <sub>PHL/</sub> t <sub>PLH</sub>	Propagation delay	2.7	R <sub>L</sub> = ∞ ; C <sub>L</sub> = 50 pF		6	13		15	ns
PHL/PLH	V <sub>is</sub> to V <sub>os</sub>	3.0 to 3.6	Figure 12		5 <sup>2</sup>	10		12	110
		4.5	-		4	9		10	
		6.0			3	8		8	
		1.2			145				
		2.0	$R_L = 1k\Omega$ ;		49	94		112	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	Turn-on time	2.7	$C_L = 50 \text{ pF}$		36	69		83	
ΨZH/ΨZL	E to V <sub>OS</sub>	3.0 to 3.6	Figures 13		28 <sup>2</sup>	55		66	
		4.5	and 1		25	47		56	
		6.0	3.1	9	19	38		43	
		1.2		~	140				ns
		2.0	$R_L = 1k\Omega;$		48	90		107	
t <sub>PZH</sub> /t <sub>PZL</sub>	Turn-on time	2.7	$C_L = 50 \text{ pF}$		35	66		79	
'PZH' 'PZL	S <sub>n</sub> to V <sub>OS</sub>	3.0 to 3.6	Figures 13		27 <sup>2</sup>	53		63	
		4.5	and 1		24	45		54	
		6.0			18	34		41	
		1.2			145				
		2.0	$R_L = 1k\Omega$		51	93		110	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn-off time	2.7	$C_L = 50  pF$		38	69		82	ns
'PHZ/'PLZ	E to V <sub>OS</sub>	3.0 to 3.6	Figures 13 and 1		30 <sup>2</sup>	56		66	115
		4.5	and 1		29	48		56	
		6.0			21	37		44	
		1.2			115				
		2.0	$R_L = 1k\Omega$		41	73		90	
t <sub>PHZ</sub> /t <sub>PLZ</sub>	Turn-off time	2.7	$C_L = 50  pF$		31	54		67	ns
'PHZ/'PLZ	S <sub>n</sub> to V <sub>OS</sub>	3.0 to 3.6	Figures 13		24 <sup>2</sup>	44		54	ns
		4.5	and 1		22	37		46	
		6.0			17	29		36	

NOTES:

1. Unless otherwise stated, all typical values are measured at  $T_{amb} = 25^{\circ}C$ 2. Typical values are measured at  $V_{CC} = 3.3 \text{ V}$ .

# 74LV4051

## **ADDITIONAL AC CHARACTERISTICS**

Recommended conditions and typical values

GND = 0 V;  $t_r = t_f \le 2.5$ ns

SYMBOL	PARAMETER	TYP.	UNIT	V <sub>CC</sub> (V)	V <sub>is(p-p)</sub> (V)	CONDITIONS
	Sine-wave distortion f = 1 kHz	0.80 0.40	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figure 9 and 10
	Sine-wave distortion f = 10 kHz	2.40 1.20	%	3.0 6.0	2.75 5.50	$R_L = 10 \text{ k}\Omega; C_L = 50 \text{ pf}$ Figure 9 and 10
	Switch "OFF" signal feed through	-50 -50	dB	3.0 6.0	Note 1	$R_L = 600 \ \Omega$ ; $C_L = 50 \ pf$ ; f= 1 MHz Figures 5 and 11
	Crosstalk between any two switches/multiplexers	-60 -60	dB	3.0 6.0	Note 1	$R_L$ = 600 Ω; $C_L$ = 50 pf; f= 1 MHz Figure 8
V <sub>(p-p)</sub>	Crosstalk voltage between enable or address input to any switch (peak-to-peak value)	110 120	mV	3.0 6.0		$R_L = 600 \Omega$ ; $C_L = 50 pf$ ; f= 1 MHz (S <sub>n</sub> or Ē, square wave between V <sub>CC</sub> and GND t <sub>r</sub> = t <sub>f</sub> = 6 ns) Figure 8
f <sub>max</sub>	Minimum frequency response (–3 dB)	180 200	MHz	3.0 6.0	Note 2	$R_L = 50 \Omega$ ; $C_L = 50 pF$ Figures 5, 8 and 9
CS	Maximum switch capacitance	5	pf		2. 3	ê 🔥
C <sub>S</sub> ENERAL N / <sub>is</sub> is the inp	Maximum switch capacitance	5 s assigne	ed as an	input.	5 7 1	Figures 5, 8 and 9

5 (dB)

0

-5

10

++++

10<sup>2</sup>

10 <sup>3</sup>

Figure 7. Typical frequency response.

10 4

f (kHz)

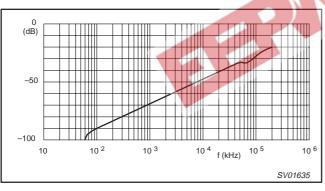
10 <sup>5</sup>

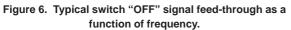
10<sup>6</sup>

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#### **GENERAL NOTES:**

- Adjust input voltage V<sub>is</sub> is 0 dBm level (0 dBm = 1 mW into 600  $\Omega$ ). 1.
- Adjust input voltage  $V_{is}$  is 0 dBm level at  $V_{OS}$  for 1 MHz (0 dBm = 1 mW into 50  $\Omega$ ). 2.





#### NOTES TO FIGURES 6 AND 7:

Test conditions: V<sub>CC</sub> = 3.0 V; GND = 0 V; V<sub>EE</sub> = -3.0 V; R<sub>L</sub> = 50  $\Omega$ ; R<sub>SOURCE</sub> = 1k $\Omega$ .

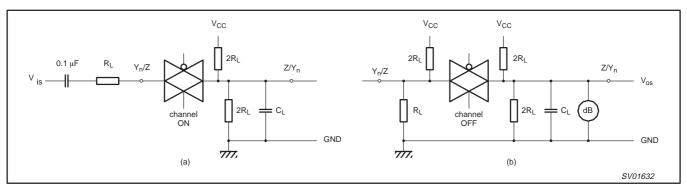


Figure 8. Test circuit for measuring crosstalk between any two switches. (a) channel ON condition; (b) channel OFF condition.

# 74LV4051

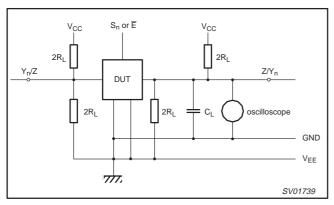


Figure 9. Test circuit for measuring crosstalk between control and any switch.

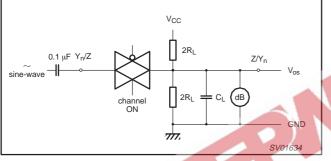


Figure 10. Test circuit for measuring minimum frequency response.

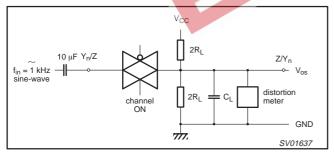
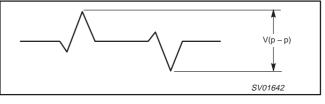


Figure 11. Test circuit for measuring sine-wave distortion.

NOTE TO FIGURE 8: The crosstalk is defined as follows (oscilloscope output):



m.cr

NOTE TO FIGURE 9: Adjust input voltage to obtain 0 dBm at V<sub>OS</sub> when  $F_{in}$  = 1 MHz. After set-up frequency of  $f_{in}$  is increased to obtain a reading of –3 dB at V<sub>OS</sub>.

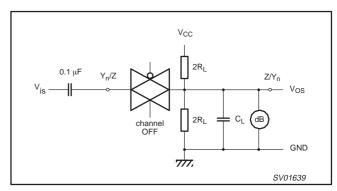


Figure 12. Test circuit for measuring switch "OFF" signal feed-through.

## 74LV4051

VM

outputs enabled

SV01640

#### **WAVEFORMS**

 $V_M$  = 1.5 V at 2.7 V  $\leq$   $V_{CC}$   $\leq$  3.6 V  $V_M$  = 0.5  $\times$   $V_{CC}$  at 2.7 V >  $V_{CC}$  > 3.6 V  $V_{OL}$  and  $V_{OH}$  are the typical output voltage drop that occur with the output load  $\begin{array}{l} \mathsf{V_X} = \mathsf{V_{OL}} + 0.3 \; \forall \; at \; 2.7 \; \forall \leq \mathsf{V_{CC}} \leq 3.6 \; \forall \\ \mathsf{V_X} = \mathsf{V_{OL}} + 0.1 \; \times \; \mathsf{V_{CC}} \; at \; 2.7 \; \forall > \mathsf{V_{CC}} > 3.6 \; \forall \\ \mathsf{V_Y} = \mathsf{V_{OH}} - 0.3 \; \forall \; at \; 2.7 \; \forall \leq \mathsf{V_{CC}} \leq 3.6 \; \forall \\ \mathsf{V_Y} = \mathsf{V_{OH}} - 0.1 \; \times \; \mathsf{V_{CC}} \; at \; 2.7 \; \forall > \mathsf{V_{CC}} > 3.6 \; \forall \\ \end{array}$ 

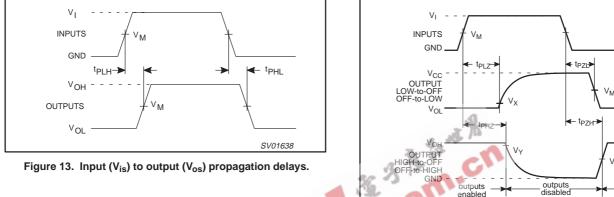


Figure 14. Turn-on and turn-off times

for the inputs  $(S_n, \overline{E})$  to the output  $(V_{os})$ .

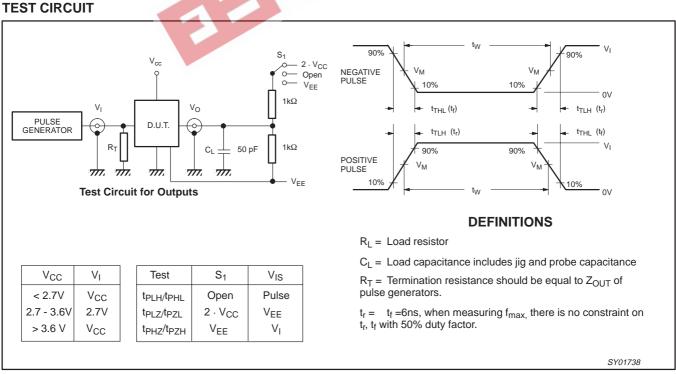
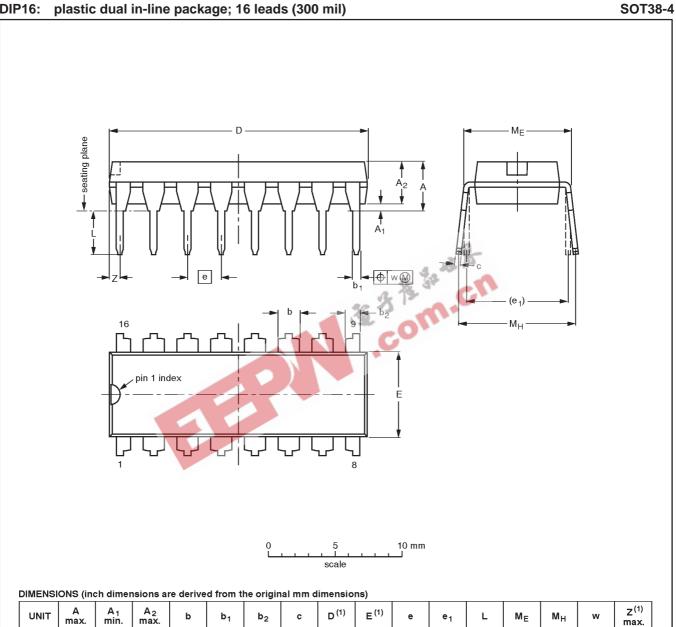


Figure 15. Load circuitry for switching times.



## DIP16: plastic dual in-line package; 16 leads (300 mil)

UNIT	A max.	A <sub>1</sub> min.	A <sub>2</sub> max.	b	b <sub>1</sub>	b <sub>2</sub>	c	D <sup>(1)</sup>	E <sup>(1)</sup>	e	e <sub>1</sub>	L	ME	M <sub>H</sub>	w	Z <sup>(1)</sup> max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	1.25 0.85	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	0.76
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.049 0.033	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.030

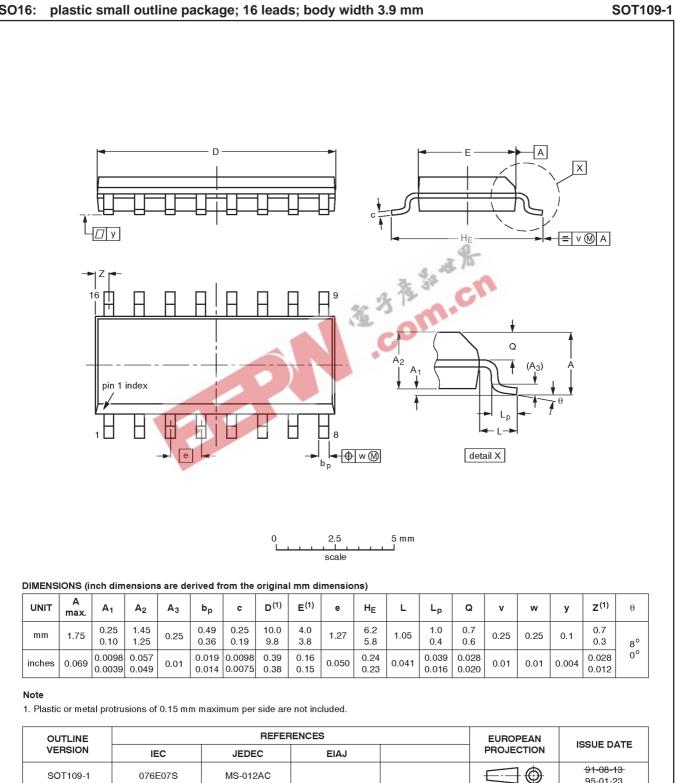
#### Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	EIAJ	PROJECTION	ISSUE DATE	
SOT38-4					<del>-92-11-17</del> 95-01-14	

Product specification

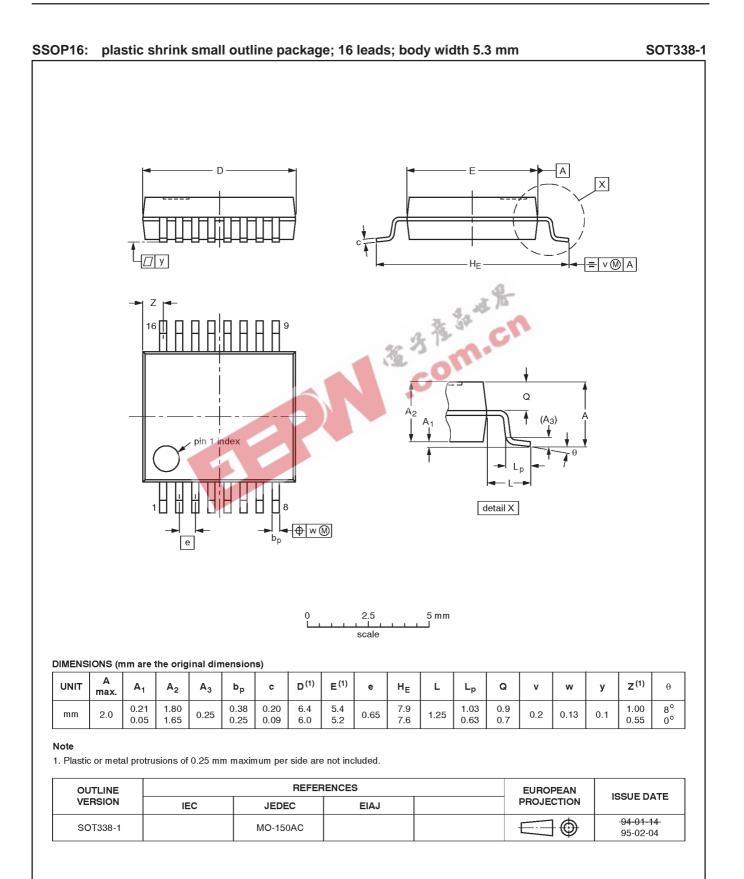
74LV4051



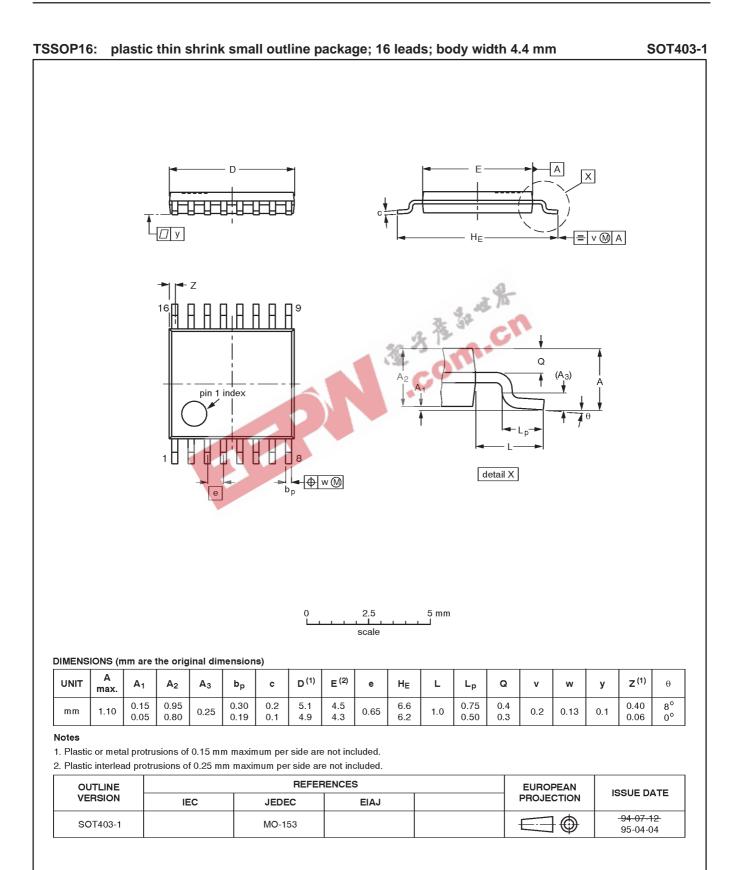
## SO16:

74LV4051

95-01-23



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Product specification

74LV4051

NOTES



## 74LV4051

DEFINITIONS		
Data Sheet Identification	Product Status	Definition
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